## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

NOV 2 9 1999

Applicant:

Leonard Forbes et al.

Serial No.:

09/256,643

Filed:

February 23, 1999

Title:

TRANSISTOR WITH

Examiner:

Group Art Unit: 2822

Docket: 303.324US2

ECTRON AFFINITY GATE AND METHODS OF FABRICATION AND USE

## SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

**Assistant Commissioner for Patents** Washington, D.C. 20231

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 et. seq., the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicants respectfully request that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants further request that a copy of the 1449 form, initialed by the Examiner to indicate that all listed citations have been considered, be returned with the next official communication.

Under 37 C.F.R. §1.97(b)(3), it is believed that no fee or certificate is required with this Information Disclosure Statement. However, if an Office Action on the merits has been mailed, the Commissioner is hereby authorized to charge any additional fees or credit any overpayment to Account No. 19-0743.

The Examiner is invited to contact the Applicants' Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

LEONARD FORBES ET AL.

By their Representatives,

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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to Assistant Commissioner of Patents, Washington, D.C. 20231 on November 1999.



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Leonard Forbes et al.

Title:

TRANSISTOR WITH VARIABLE ELECTRON AFFINITY GATE AND METHODS OF FABRICATION AND

USE

Docket No.:

303.324US2

Filed:

February 23, 1999

Examiner:

Serial No.: 09/256,643

Due Date: December 23, 1999

Group Art Unit: 2822

Assistant Commissioner for Patents

Washington, D.C. 20231

We are transmitting herewith the following attached items (as indicated with an "X"):

A return postcard.

X A Supplemental Information Disclosure Statement (1 pgs.), Form 1449 (1 pgs.), and copies of 2 cited references.

Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional required fees or credit overpayment to Deposit Account No. 19-0743.

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this Transmittal Letter and the paper, as described above, are being deposited in the United States Postal Service, as first class mail, in an envelope addressed to: Assistant formulasioner for Patents, Washington, D.C. 20231, on this 23<sup>th</sup> day of November, 1999.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

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Atty: Robert 1

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